



Compact, Single-Sided High Heat Dissipation Molded Power Modules for Traction Inverter Drive

TRC(ti: ar sf:) DRIVE(dráiv) pack(pæk)]

Achieves ultra-high current density

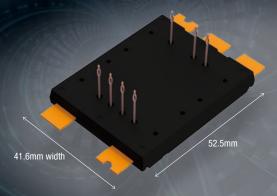
(compact + Capable of high current)

Low inductance and switching loss

Equipped with Low ON resistance 4th Gen SiC MOSFETs

Compact easy-to-mount single-sided high heat dissipation molded package

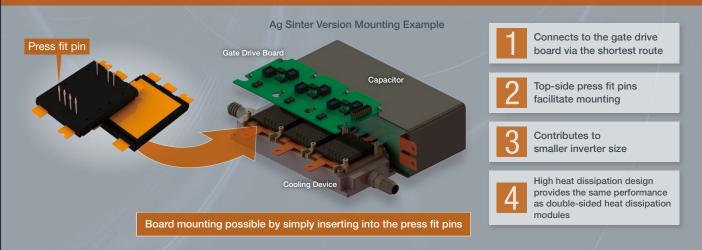
Adopts a top-side press fit pin structure



A type (Small) package 22cm² size A type (Large) package 31cm² size

Advantages of single-sided high heat dissipation package with top-side press fit pins

58.6mm width



<u>52.5</u>mm

TRCDRIVE pack[™] Features

Low inductance enables high current density

TRCDRIVE pack[™] reduces switching losses by optimizing the internal layout to achieve an extremely small inductance of 5.7nH. Incorporating low ON resistance 4th Generation SiC MOSFETs results in an industry-leading current density of 19.1Arms/cm² (BST780D12P4A163), with an output current greater than 600Arms for both 750V rated (e.g. BST740D08P4A154) and 1200V rated (e.g. BST780D12P4A163) models.

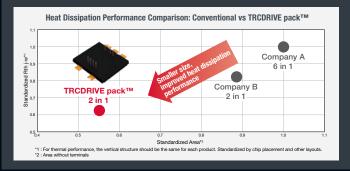


Two evaluation kits enable immediate evaluation

Compact single-sided heat dissipation molded package

TRCDRIVE pack[™] delivers equivalent heat dissipation performance to that of competitor's products in a smaller single-sided heat dissipation design through a proprietary molded module structure.

The 12-model lineup features top-side press fit pins in different package sizes (small/large) and mounting patterns (TIM : heat dissipation sheet, Ag sinter) to support quick adoption in a wider range of applications.



ROHM offers two types of evaluation kits (EVKs) for double-pulse and 3-Phase Full Bridge. We support customer evaluations with a wide range of solutions, including simulations and thermal designs. For details, please contact a sales representative.

TRCDRIVE pack[™] Evaluation kits (EVKs) with 4th Gen SiC MOSFETs

EVK for Double-pulse Test EVK for 3-Phase Full Bridge Pre-connected screw-fastened external Pre-welded screw-fastened external terminals eliminates the need for terminals eliminates the need for additional terminal welding additional terminal welding No dedicated capacitors are required, Dedicated pre-welded capacitors (low Ls) enabling evaluation in standard various •Built-in cooling system environments Gate Driver Board Supply: 24V Typ Gate Driver Board Supply: 24V Typ Switching Frequency: up to 20kHz Switching Frequency: up to 20kHz Working Voltage: Depends on the Working Voltage: up to 900V withstand voltage of the capacitor/device

TRCDRIVE pack[™] Lineup

Part No.	Absolute Maximum Ratings(Tj=25°C)					Heat Sink			Built-in		AQG 324
	V _{DSS} [V]	R _{DS(on)} [mΩ]	DC Current [A]*1	AC Current [A]*2	Tj [°C]	Assembly		Module Type	MOSFET	Topology	Qualified
New BST500D08P4A104	750	2.0	506	417		TIM: heat dissipation sheet	Small	A type (Small)		Half bridge	
☆ BST500D08P4A114				429		Ag Sinter		41.6mm 52.5mm	- 4th Gen. SiC MOSFET	8 - 2 6 - 4.5 9 - 4.5 12 - NRC	Yes
New BST400D12P4A101	1,200	2.8	394	326		TIM: heat dissipation sheet					
☆ BST400D12P4A111				336		Ag Sinter					
New BST740D08P4A154	750	1.4	738	634	-40 to +175	TIM: heat	- Large	A type (Large)			
☆ BST1040D08P4A156		1.0	1,039	736		dissipation sheet					
☆ BST740D08P4A164		1.4	738	659		Ag Sinter					
☆ BST1040D08P4A166		1.0	1,039	771							
New BST580D12P4A151	1,200	1.9	575	475		TIM: heat					
☆ BST780D12P4A153		1.2	778	571		dissipation sheet					
☆ BST580D12P4A161		1.9	575	494		Ag Sinter	3				
☆ BST780D12P4A163		1.2	778	593							
*1 T _c =60°C, V _{GS} =18V										s∕⊳: Under	Development

*2 Tf=65°C, Vpc=800V/500V, fsw=10kHz, Modulation=0.9, Power factor=0.9

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